The Development and the commercialization of the Mask Aligner for wafer Midas System will continue to grow along with the value creation for our customers.

http://www.aligner.co.kr





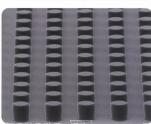
The MDA-12SA is brand new model and represents next generation of Full-field lithography systems. This brand new Semi-auto Aligner platform offers a higher Overlay Accuracy and more reliable operation. It is good for Ceramic, other Probe Card and WLP applications, This machine has higher productivity and easy to control.











ITEM	SPECIFICATIONS
Substrate Size	Up to 12 inch
UV Lamp Power	2 kW
Resolution	down to 3μm (※FT=1μm @ 12 inch Si Wafer)
Alignment Accuracy	$\pm 3 \mu$ m
Lamp Uniformity	≤± 5%
Uniform Beam Size	14.25" × 14.25"
365nm Beam Intensity	$15\sim$ 20mW/cm² (Broad band)
Exposure Time	$0.1\sim999.9~{ m sec}$
Motorized	Microscope X, Y -axis, Zoom and Focus Stage X, Y, θ and Z-axis
Process mode	Vacuum, Hard, Soft and Proximity
Dimension	$1,700 \times 1,500 \times 2,100 \text{ mm}$

